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LMX2582 High Performance, Wideband PLLatinum™ RF Synthesizer with Integrated VCO

Technical [Documents](http://www.ti.com/product/LMX2582?dcmp=dsproject&hqs=td&#doctype2)

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	- GHz Output **devices** in high performance systems.
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- Programmable Charge Pump Current
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- • Test/Measurement Equipment
- Cellular Base-station
- **Microwave Backhaul**
- High-Performance Clock Source for High-Speed
Data Converters
-

1 Features 3 Description

Tools & **[Software](http://www.ti.com/product/LMX2582?dcmp=dsproject&hqs=sw&#desKit)**

1 Output Frequency Range from 20 to 5500 MHz

integrated VCO that supports a frequency range from Industry Leading Phase Noise Performance

• Industry Leading Phase Noise Performance

• Industry Leading Phase Noise: -144.5 dBc/Hz at 1-MHz to 5.5 GHz. The device supports both VCO Phase Noise: –144.5 dBc/Hz at 1-MHz fractional-N and integer-N modes, with a 32-bit
Offset for 1.8 GHz Output fractional divider allowing fine frequency selection. fractional divider allowing fine frequency selection. - Normalized PLL Noise Floor: -231 dBc/Hz **health integrated noise of 47 fs for 1.8 GHz output makes it** an ideal low noise source. Combining best-in-class – Normalized PLL Flicker Noise: –126 dBc/Hz
PLL and integrated VCO noise with integrated LDOs,
– 47 fs RMS Jitter (12 kHz to 20 MHz) for 1.8 this device removes the need for multiple discrete this device removes the need for multiple discrete

Input Clock Frequency up to 1400 MHz The device accepts input frequencies up to 1.4 GHz, • Phase Detector Frequency up to 200 MHz, which combined with frequency dividers and and up to 400 MHz in Integer-N Mode

Frequency planning. The additional programmable low

Frequency planning. The additional programmable low Supports Fractional-N and Integer-N Modes
• noise multiplier lets users mitigate the impact of
• integer houndary spurs In Fractional-N mode the impact of integer boundary spurs. In Fractional-N mode, the • Innovative Solution to Reduce Spurs device can adjust the output phase by a 32-bit resolution. For applications that need fast frequency • < 25-µs Fast Calibration Mode changes, the device supports a fast calibration option • Programmable Phase Adjustment which takes less than ²⁵ us.

This performance is achieved by using single 3.3-V Programmable Output Power Level

supply. It supports 2 flexible differential outputs that

SPI or uWire (4-Wire Serial Interface)

can be configured as single-ended outputs as well. can be configured as single-ended outputs as well. • Single Power Supply Operation: 3.3 V Users can choose to program one output from the VCO and the second from the channel divider. When not being used, each output can be muted **² Applications** separately.

Device Information [\(1\)](#page-0-0)

- (1) For all available packages, see the orderable addendum at • Software Defined Radio Software Defined Radio the end of the datasheet.
	- (2) $T = \text{Tape}$; $R = \text{Reel}$

Simplified Schematic

Table of Contents

4 Revision History

Changes from Original (December 2015) to Revision A Page • Changed device status from product preview to production data, and released full data sheet ... [1](#page-0-3)

5 Pin Configuration and Functions

Pin Functions

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Pin Functions (continued)

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *[Recommended](#page-4-3) Operating [Conditions](#page-4-3)*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions. Pins listed as ±2500 V may actually have higher performance.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions. Pins listed as ±1250 V may actually have higher performance.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

6.4 Thermal Information

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report ([SPRA953](http://www.ti.com/lit/pdf/spra953)).

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6.5 Electrical Characteristics

3.15 V ≤ V_{CC} ≤ 3.45 V, -40°C ≤ T_A ≤ 85°C.

Typical values are at V_{CC} = 3.3 V, 25°C (unless otherwise noted)

- (2) For a typical high output power for a single-ended output, with 50-Ω pull-up on both M and P side, register OUTx_POW = 63. Un-used side terminated with 50- Ω load.
- (3) There is internal voltage biasing so the OSCinM and OSCinP pins should always be AC coupled (capacitor in series). Vppd is differential peak-to-peak voltage swing. If there is a differential signal (two are negative polarity of each other), the total swing is one subtracted by the other, each should be 0.1 to 1-Vppd. If there is a single-ended signal, it can have 0.2 to 2Vppd. See Detailed Description and Applications section for more information.
- (4) To use phase detector frequencies lower than 5 MHz set register FCAL_LPFD_ADJ = 3. To use phase detector frequencies higher than 200MHz, you must be in integer mode, set register PFD_CTL = 3 (to use single PFD mode), set FCAL_HPFD_ADJ = 3. To see more information go to Detailed Description section.
- (5) The PLL noise contribution is measured using a clean reference and a wide loop bandwidth and is composed into flicker and flat components. PLL_flat = PLL_FOM + 20*log(Fvco/Fpd) + 10*log(Fpd / 1Hz). PLL_flicker (offset) = PLL_flicker_Norm + 20*log(Fvco / 1GHz) – 10*log(offset / 10kHz). Once these two components are found, the total PLL noise can be calculated as PLL_Noise =
10*log(10^{PLL_Flat / 10} + 10^{PLL_flicker / 10}).
- Not tested in production. Ensured by characterization. Allowable temperature drift refers to programming the device at an initial temperature and allowing this temperature to drift without reprogramming the device, and still have the device stay in lock. This change could be up or down in temperature and the specification does not apply to temperatures that go outside the recommended operating temperatures of the device.

⁽¹⁾ For typical total current consumption of 250 mA: 100 MHz input frequency, OSCin doubler bypassed, pre-R divider bypassed, multiplier bypassed, post-R divider bypassed, 100MHz phase detector frequency, 0.468mA charge pump current, channel divider off, one output on, 5.4GHz output frequency, 50-Ω output pull-up, 0 dBm output power (differential). See Applications section for more information.

Electrical Characteristics (continued)

 $3.15 \text{ V} \leq \text{V}_{\text{CC}} \leq 3.45 \text{ V}, -40^{\circ}\text{C} \leq \text{T}_{A} \leq 85^{\circ}\text{C}.$

Typical values are at V_{CC} = 3.3 V, 25°C (unless otherwise noted)

6.6 Timing Requirements

3.15 V ≤ V_{CC} ≤ 3.45 V, -40°C ≤ T_A ≤ 85°C, except as specified. Typical values are at V_{CC} = 3.3 V, T_A = 25°C

Figure 1. Serial Data Input Timing Diagram

There are several considerations for programming:

- A slew rate of at least 30 V/µs is recommended for the CLK, DATA, LE
- The DATA is clocked into a shift register on each rising edge of the CLK signal. On the rising edge of the LE signal, the data is sent from the shift registers to an actual counter
- The LE pin may be held high after programming and clock pulses will be ignored
- The CLK signal should not be high when LE transitions to low
- When CLK and DATA lines are shared between devices, it is recommended to divide down the voltage to the CLK, DATA and LE pins closer to the minimum voltage. This provides better noise immunity
- If the CLK and DATA lines are toggled while the VCO is in lock, as is sometimes the case when these lines are shared with other parts, the phase noise may be degraded during the time of this programming

6.7 Typical Characteristics

 $T_A = 25^{\circ}$ C (unless otherwise noted)

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Typical Characteristics (continued)

 $T_A = 25^{\circ}$ C (unless otherwise noted)

Typical Characteristics (continued)

 $T_A = 25^{\circ}$ C (unless otherwise noted)

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7 Detailed Description

7.1 Overview

The LMX2582 is a high performance wideband synthesizer (PLL with integrated VCO). The output frequency range is from 20 MHz to 5.5 GHz. The VCO core covers an octave from 3.55 to 7.1 GHz. The output channel divider covers the frequency range from 20MHz to the low bound of the VCO core.

The input signal frequency has a wide range from 5 to 1400MHz. Following the input, there is an programmable OSCin doubler, a pre-R divider (previous to multiplier), a multiplier, and then a post-R divider (after multiplier) for flexible frequency planning between the input (OSCin) and the phase detector.

The phase detector (PFD) can take frequencies from 5 to 200 MHz, but also has extended modes down to 0.25 MHz and up to 400 MHz. The phase-lock loop (PLL) contains a Sigma-Delta modulator (1st to 4th order) for fractional N-divider values. The fractional denominator is programmable to 32-bit long, allowing a very fine resolution of frequency step. There is a phase adjust feature that allows shifting of the output phase in relation to the input (OSCin) by a fraction of the size of the fractional denominator.

The output power is programmable and can be designed for high power at a specific frequency by the pull-up component at the output pin.

The digital logic is a standard 4-wire SPI or uWire interface and is 1.8-V and 3.3-V compatible.

7.2 Functional Block Diagram

7.3 Functional Description

7.3.1 Input Signal

An input signal is required for the PLL to lock. The input signal is also used for the VCO calibration, so a proper signal needs to be applied before the start of programming. The input signal goes to the OSCinP and OSCinM pins of the device (there is internal biasing which requires AC-coupling caps in series before the pin). This is a differential buffer so the total swing is the OSCinM signal subtracted by the OSCinP signal. Both differential signals and single-ended signal can be used. Below is an example of the max signal level in each mode. It is important to have proper termination and matching on both sides (see *Application and [Implementation](#page-25-0)*).

Functional Description (continued)

7.3.2 Input Signal Path

The input signal path contains the components between the input (OSCin) buffer and the phase detector. The best PLL noise floor is achieved with a 200-MHz input signal for the highest dual phase detector frequency. In order to address a wide range of applications, the input signal path contains the below components for flexible configuration before the phase detector. Each component can be bypassed. See the table below for usage boundaries if engaging a component.

- OSCin doubler: This is low noise frequency doubler which can be used to multiply input frequencies by two. The doubler uses both the rising and falling edge of the input signal so the input signal must have 50% duty cycle if enabling the doubler. The best PLL noise floor is achieved with 200-MHz PFD, thus the doubler is useful if, for example, a very low noise 100-MHz input signal is available instead.
- Pre-R divider: This is a frequency divider capable of very high frequency inputs. Use this to divide any input frequency up to 1400-MHz, and then the post-R divider if lower frequencies are needed.
- Multiplier: This is a programmable, low noise multiplier. In combination with the Pre-R and Post-R dividers, the multiplier offers the flexibility to set a PFD away from frequencies that may create critical integer boundary spurs with the VCO and output frequencies. See *Application and [Implementation](#page-25-0)* for an example. The user should not use the doubler while using the low noise programmable multiplier.

• Post-R divider: Use this divider to divide down to frequencies below 5 MHz in extended PFD mode.

Table 1. Boundaries for Input Path Components

7.3.3 PLL Phase Detector and Charge Pump

The PLL phase detector, also known as phase frequency detector (PFD), compares the outputs of the post-R divider and N divider and generates a correction current with the charge pump corresponding to the phase error until the two signals are aligned in phase (the PLL is locked). The charge pump output goes through external components (loop filter) which turns the correction current pulses into a DC voltage applied to the tuning voltage (Vtune) of the VCO. The charge pump gain level is programmable and allow to modify the loop bandwdith of the PLL.

The default architecture is a dual-loop PFD which can operate between 5 to 200 MHz. To use it in extended range mode the PFD has to be configured differently:

- Extended low phase detector frequency mode: For frequencies between 250 kHz and 5 MHz, low PFD mode can be activated (FCAL_LPFD_ADJ = 3). PLL_N_PRE also needs to be set to 4.
- Extended high phase detector frequency mode: For frequencies between 200 and 400 MHz, high PFD mode can be activated (FCAL_HPFD_ADJ = 3). The PFD also has to be set to single-loop PFD mode (PFD_CTL = 3). This mode only works if using integer-N, and PLL noise floor will be about 6-dB higher than in dual-loop PFD mode.

7.3.4 N Divider and Fractional Circuitry

The N divider (12 bits) includes a multi-stage noise shaping (MASH) sigma-delta modulator with prgrammable order from 1st to 4th order, which performs fractional compensation and can achieve any fractional denominator from 1 to $(2^{32} - 1)$. Using programmable registers, PLL_N is the integer portion and PLL_NUM / PLL_DEN is the fractional portion, thus the total N divider value is determined by PLL_N + PLL_NUM / PLL_DEN. This allows the output frequency to be a fractional multiplication of the phase detector frequency. The higher the denominator the finer the resolution step of the output. There is a N divider prescalar (PLL_N_PRE) between the VCO and the N divider which performs a division of 2 or 4. 2 is selected typically for higher performance in fractional mode and 4 may be desirable for lower power operation and when N is approaching max value.

Fvco = Fpd x PLL_N_PRE x (PLL_N + PLL_NUM / PLL_DEN)

Minimum output frequency step = Fpd / PLL_DEN

Typically, higher modulator order pushes the noise out in frequency and may be filtered out with the PLL. However, several tradeoff needs to be made. table below shows the suggested minimum N value while in fractional mode as a function of the sigma-delta modulator order. It also describe the recommended register setting for the PFD delay (register PFD DLY SEL).

Table 2. MASH order and N Divider

7.3.5 Voltage Controlled Oscillator

The voltage controlled oscillator (VCO) is fully integrated. The frequency range of the VCO is from 3.55 to 7.1 GHz so it covers one octave. Output dividers allow the generation of all other lower frequencies. The output frequency of the VCO is inverse proportional to the DC voltage present at the tuning voltage point on pin Vtune. The tuning range is $0 \vee$ to 2.5 V. 0 V generates the maximum frequency and 2.5 V generates the minimum frequency. This VCO requires a calibration procedure for each frequency selected to lock on. Each vco calibration will force the tuning voltage to mid value and calibrate the VCO circuit. The VCO is designed to remained locked over the entire temperature range the device can support. [Table](#page-13-0) 3 shows the VCO gain as a function of frequency.

Table 3. Typical kVCO

7.3.6 VCO Calibration

The VCO calibration is responsible of setting the VCO circuit to the target frequency. The frequency calibration routine is activated any time that the R0 register is programmed with the FCAL EN = 1. A valid input (OSCin) signal to the device must present before the VCO calibration begins. To see how to reduce the calibration time, refer to *Application and [Implementation](#page-25-0)*.

7.3.7 Channel Divider

Figure 19. Channel Divider Diagram

To go below the VCO lower bound, the channel divider must be used. The channel divider consists of three programmable dividers controlled by the registers CHDIV_SEG1, CHDIV_SEG2, CHDIV_SEG3. The Multiplexer (programmed with register CHDIV_SEG_SEL) selects which divider is included in the path. The minimum division is 2 while the maximum division is 192. Un-used dividers can be powered down to save current consumption. The entire channel divider can be powered down with register CHDIV_EN = 0 or selectively setting registers CHDIV_SEG1_EN = 0, CHDIV_SEG2_EN = 0 ,CHDIV_SEG3_EN = 0. Unused buffers may also be powered down with registers CHDIV_DISTA_EN and CHDIV_DIST_EN. See [Table](#page-14-0) 4 for a guideline of what channel divider setting to use when below a specific output frequency.

OUTPUT FREQUENCY	CHANNEL DIVIDER SEG1	CHANNEL DIVIDER SEG ₂	CHANNEL DIVIDER SEG ₃	TOTAL DIVISION	VCO FREQ
3600	2			$\overline{2}$	7200
1840	3		1	3	5520
1240	$\overline{2}$	2	1	4	4960
930	3	$\overline{2}$	1	6	5580
610	$\overline{2}$	4	1	8	4880
460	$\overline{2}$	6	1	12	5520
300	$\overline{2}$	8	1	16	4800
230	3	8	1	24	5520
150	$\mathbf{2}$	8	2	32	4800
110	3	6	$\overline{2}$	36	3960
100	3	8	$\overline{2}$	48	4800
70	$\overline{2}$	8	4	64	4480
50	2	8	6	96	4800
30	$\overline{2}$	8	8	128	3840
20	3	8	8	192	3840

Table 4. Channel Divider Setting as a Function of the Desired Output Frequency

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7.3.8 Output Distribution

Figure 20. Output Distribution Diagram

For each output A or B, there is a mux which select the VCO output directly or the channel divider output. Before these selection MUX there are several buffers in the distribution path which can be configured depending on the route selected. By disabling unused buffers, unwanted signals can be isolated and unneeded current consumption can be eliminated.

7.3.9 Output Buffer

Each output buffer (A and B) have programmable gain with register OUTA_POW and OUTB_POW. The RF output buffer configuration is open collector and requires an external pull-up from RFout pin to V_{CC} . There are two pull-up options that can be used with either resistor or inductor. Refer to the applications section for design considerations.

- 1. Resistor pull-up: placing a 50-Ω resistor pull-up matches the output impedance to 50-Ω. However, maximum output power is limited. Output buffer current settings should be set to a value before output power is saturated (output power increases less for every step increase in output current value).
- 2. Inductor pull-up: placing an inductor pull-up creates a resonance at the frequency of interest. This offers higher output power for the same current and higher maximum output power. However, the output impedance will be higher and additional matching may be required..

7.3.10 Phase Adjust

In fractional mode, the phase relationship between the output and the input can be changed with very fine resolution. Writing the register MASH_SEED will trigger this shift. The seed value should be less then the fractional-N denominator register PLL_N_DEN. The actual phase shift can be obtained with the following equation:

Phase shift (degrees) = $360 \times MASH$ SEED / PLL N DEN / [Channel divider value]

7.4 Device Functional Modes

7.4.1 Powerdown

Power up and down can be achieved using the CE pin (logic HIGH or LOW voltage) or the POWERDOWN register bit (0 or 1). When the device comes out of the powered down state, either by pulling back CE pin HIGH (if it was powered down by CE pin) or by resuming the POWERDOWN bit to 0 (if it was powered down by register write), it is required that register R0 be programmed again to re-calibrate the device.

Device Functional Modes (continued)

7.4.2 Lock Detect

The MUXout pin can be configured to output a signal that gives an indication for the PLL being locked. If lock detect is enabled (LD_EN = 1) and the MUXout pin is configured as lock detect output (MUXOUT_SEL = 1), when the device is locked, the MUXout pin output is a logic HIGH voltage, and when the device is unlocked, MUXout output is a logic LOW voltage.

7.4.3 Register Readback

The MUXout pin can be programmed (MUXOUT_SEL = 0) to use register readback serial data output. To read back a certain register value, use the following steps:

- 1. Set the R/W bit to 1; the data field contents are ignored.
- 2. Program this register to the device, readback serial data will be output starting at the 9th clock.

Figure 21. Register Readback Timing Diagram

7.5 Programming

The programming using 24-bit shift registers. The shift register consists of a R/W bit (MSB), followed by a 7-bit address field and a 16-bit data field. For the R/W (bit 23), 1 is read and 0 is write. The address field ADDRESS (bits 22:16) is used to decode the internal register address. The remaining 16 bits form the data field DATA (bits 15:0). While CSB is low, serial data is clocked into the shift register upon the rising edge of clock (data is programmed MSB first). When CSB goes high, data is transferred from the data field into the selected register bank.

7.5.1 Recommended Initial Power on Programming Sequence

When the device is first powered up, the device needs to be initialized and the ordering of this programming is very important. After this sequence is completed, the device should be running and locked to the proper frequency.

- 1. Apply power to the device and ensure the V_{CC} pins are at the proper levels
- 2. Ensure that a valid reference is applied to the OSCin pin
- 3. Soft reset the device (write R0[1] = 1)
- 4. Program the remaining registers
- 5. Frequency calibrate (write R0[3] = 1)

7.5.2 Recommended Sequence for Changing Frequencies

The recommended sequence for changing frequencies is as follows:

- 1. Set the new N divider value (write R38[12:1])
- 2. Set the new PLL numerator (R45 and R44) and denominator (R41 and R40)
- 3. Frequency calibrate (write R0[3] = 1)

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7.6 Register Maps

7.6.1 LMX2582 Register Map

Figure 22. Register Table

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7.6.1.1 Register Descriptions

Table 5. R0 Register Field Descriptions

Table 7. R7 Register Field Descriptions

Table 8. R8 Register Field Descriptions

Table 9. R9 Register Field Descriptions

to 200MHz as possible if fast calibration time is desired.

Table 10. R10 Register Field Descriptions

Table 11. R11 Register Field Descriptions

Table 12. R12 Register Field Descriptions

Table 13. R13 Register Field Descriptions

Table 14. R14 Register Field Descriptions

Table 15. R19 Register Field Descriptions

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Table 25. R35 Register Field Descriptions (continued)

Table 26. R36 Register Field Descriptions

Table 27. R37 Register Field Descriptions

Table 28. R38 Register Field Descriptions

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Table 37. R47 Register Field Descriptions

Table 38. R48 Register Field Descriptions

Table 39. R64 Register Field Descriptions

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

8.1.1 Optimization of Spurs

8.1.1.1 Understanding Spurs by Offsets

The first step in optimizing spurs is to be able to identify them by offset. [Figure](#page-25-2) 23 gives a good example that can be used to isolate the following spur types.

Figure 23. Spur Offset Frequency Example

Based on the above figure, the most common spurs can be calculated from the frequencies. Note that the **%** is the modulus operator and is meant to mean the difference to the closest integer multiple. Some examples of how to use this operator are: 36 % 11 = 3, 1000.1 % 50 = 0.1, and 5023.7 % 122.88 = 14.38. Applying this concept, the spurs at various offsets can be identified from [Figure](#page-25-2) 23.

Table 40. Spur Definition Table

Application Information (continued)

Table 40. Spur Definition Table (continued)

In the case that two different spur types occur at the same offset, either name would be correct. Some may name this by the more dominant cause, while others would simply name by choosing the name that is near the top of [Table](#page-25-3) 40.

8.1.1.2 Spur Mitigation Techniques

Once the spur is identified and understood, there will likely be a desire to try to minimize them. The following table gives some common methods.

Table 41. Spurs and Mitigation Techniques

Table 41. Spurs and Mitigation Techniques (continued)

8.1.2 Configuring the Input Signal Path

The input path is considered the portion of the device between the OSCin pin and the phase detector, which includes the input buffer, R dividers, and programmable multipliers. The way that these are configured can have a large impact on phase noise and fractional spurs.

8.1.2.1 Input Signal Noise Scaling

The input signal noise scales by 20*log(output frequency / input signal frequency), so always check this to see if the noise of the input signal scaled to the output frequency is close to the PLL in-band noise level. When that happens, the input signal noise is the dominant noise source, not the PLL noise floor.

8.1.3 Input Pin Configuration

The OSCinM and OSCinP can be used to support both a single-ended or differential clock. In either configuration, the termination on both sides should match for best common-mode noise rejection. The slew rate and signal integrity of this signal can have an impact on both the phase noise and fractional spurs. Standard clocking types, LVDS, LVPECL, HCSL, and CMOS can all be used.

8.1.4 Using the OSCin Doubler

The lowest PLL flat noise is achieved with a low noise 200-MHz input signal. If only a low noise input signal with lower frequency is available (for example a 100-MHz source), you can use the low noise OSCin doubler to attain 200-MHz phase detector frequency. Since PLL_flat = PLL_FOM + 20*log(Fvco/Fpd) + 10*log(Fpd / 1Hz), doubling Fpd theoretically gets –6 dB from the 20*log(Fvco/Fpd) component, +3 dB from the 10*log(Fpd / 1Hz) component, and cumulatively a –3-dB improvement.

Figure 26. 100MHz Input with OSCin Doubler

8.1.5 Using the Input Signal Path Components

The ideal input is a low noise 200-MHz (or multiples of it) signal and 200-MHz phase detector frequency (highest dual PFD frequency). However, if spur mechanisms are understood, certain combinations of the R-divider and Multiplier can help. Refer to the optimization of spurs section for understanding spur types and their mechanisms first, then try this section for these specific spurs.

8.1.5.1 Moving Phase Detector Frequency

Engaging the multiplier in the reference path allows more flexibility in setting the PFD frequency. One example use case of this is if Fvco % Fpd is the dominant spur. This method can move the PFD frequency and thus the Fvco % Fpd.

Example: Fvco = 3720.12 MHz, Fosc = 300 MHz, Pre-R divider = 5, Fpd = 60 MHz, Fvco%Fosc = 120.12 MHz (Far out), Fvco%Fpd = 120 kHz (dominant). There is a Fvco%Fpd spur at 120 kHz (refer to [Figure](#page-28-0) 27).

Figure 27. Fvco % Fpd Spur

Then second case, using divider and multiplier, we make Fpd = 53.57 MHz away from 120-kHz spur. Fvco = 3720.12 MHz, Fosc = 300 MHz, Pre-R divider = 7, Multiplier = 5, Post-R divider = 4, Fpd = 53.57 MHz, Fvco%Fosc = 120.12 MHz (Far out). Fvco % Fpd = 23.79 MHz (far out). There is a 20–dB reduction for the Fvco % Fpd spur at 120 kHz (refer to [Figure](#page-29-0) 28).

Figure 28. Moving Away from Fvco % Fpd Spur

8.1.5.2 Multiplying and Dividing by the Same Value

Although it may not seem like the first thing to try, the Fvco%Fosc and Fout%Fosc spur can sometimes be improved engaging the OSC_2X bit and then dividing by 2. Although this gives the same phase detector frequency, the spur can be improved.

8.1.6 Designing for Output Power

If there is a desired frequency for highest power, use an inductor pull-up and design for the value so that the resonance is at that frequency. Use the formula SRF = $1 / (2\pi x \sqrt{E} \cdot E)$.

Example: $C = 1.4$ pF (characteristic). If max power is targeted at 1 GHz, $L = 18$ nH. If max power is targeted at 3.3 GHz, $L = 1.6$ nH

Figure 29. Output Power Versus Pull-Up Type

8.1.7 Current Consumption Management

The starting point is the typical total current consumption of 250 mA: 100-MHz input frequency, OSCin doubler bypassed, Pre-R divider bypassed, multiplier bypassed, post-R divider bypassed, 100-MHz phase detector frequency, 0.468-mA charge pump current, channel divider off, one output on, 5400-MHz output frequency, 50-Ω output pull-up, 0-dBm output power (differential). To understand current consumption changes due to engaging different fuctional blocks , refer to [Table](#page-29-1) 42.

ACTION	STEPS	PROGRAMMING	INCREASE IN CURRENT (mA)
Add an output	Route VCO to output B	VCO DISTB $PD = 0$	
	Enable output B buffer	$OUTB$ $PD = 0$	54
Increase output power from 0 to +10dBm (differential)	Set highest output buffer current	OUTA POW = 63	53
Use channel divider	Route channel divider to output	CHDIV DISTA $EN = 1$	5
	Enable channel divider	CHDIV $EN = 1$	18
	Enable chdiv_seg1	CHDIV SEG1 $EN = 1$	2
	Enable chdiv seg2	CHDIV SEG2 $EN = 1$	5
	Enable chdiv seg3	CHDIV SEG3 $EN = 1$	

Table 42. Typical Current Consumption Impact By Function (continued)

8.1.8 Decreasing Lock Time

Lock time consists of the calibration time (time for internal algorithm to set to desired output frequency) plus the analog settling time (time to settle to the final Vtune value). For fast calibration set registers FCAL_FAST = 1 and ACAL FAST = 1. Also set the calibration clock (input frequency / 2 \triangle CAL CLK DIV) close to the maximum (200 MHz). For fast analog settling time, design loop filter for very wide loop bandwidth (MHz range).

Figure 30. Lock Time Screenshot

The calibration sweeps from the top of the VCO frequency range to the bottom. This example does a calibration to lock at 3.7 GHz (which is the worst case). For the left screenshot (Wideband Frequency view), see the sweeping from top to bottom of the VCO range. On the right screenshot (Narrowband Frequency view), see the analog settling time to the precise target frequency.

8.1.9 Modeling and Understanding PLL FOM and Flicker Noise

Follow these recommended settings to design for wide loop bandwidth and extract FOM and flicker noise. The flat model is the PLL noise floor modeled by: PLL_flat = PLL_FOM + 20*log(Fvco/Fpd) + 10*log(Fpd / 1 Hz). The flicker noise (also known as 1/f noise) which changes by -10dB / decade, is modeled by: PLL_flicker (offset) = PLL_flicker_Norm + 20*log(Fvco / 1 GHz) – 10*log(offset / 10k Hz). The cumulative model is the addition of both components: PLL_Noise = 10 *log(10PLL_Flat / 10 + 10PLL_flicker / 10). This is adjusted to fit the the measured data to extract the PLL_FOM and PLL_flicker_Norm spec numbers.

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NSTRUMENTS

EXAS

8.2 Typical Application

8.2.1 Design for Low Jitter

Figure 32. Typical Application Schematic

8.2.1.1 Design Requirements

Refer to the design parameters shown in [Table](#page-32-1) 44.

Table 44. Design Information

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8.2.1.2 Detailed Design Procedure

The integration of phase noise over a certain bandwidth (jitter) is an performance specification that translates to signal-to-noise ratio. Phase noise inside the loop bandwidth is dominated by the PLL, while the phase noise outside the loop bandwidth is dominated by the VCO. As a rule of thumb, jitter will be lowest if loop bandwidth is designed to the point where the two intersect. A higher phase margin loop filter design will have less peaking at the loop bandwidth and thus lower jitter. The tradeoff with this as longer lock times and spurs should be considered in design as well.

8.2.1.3 Application Curves

9 Power Supply Recommendations

It is recommended to place 100 nF close to each of the power supply pins. If fractional spurs are a large concern, using a ferrite bead to each of these power supply pins can reduce spurs to a small degree.

10 Layout

10.1 Layout Guidelines

See EVM instructions for details. In general, the layout guidelines are similar to most other PLL devices. The followings are some outstanding guidelines.

- Place output pull up components close to the pin.
- Place capacitors close to the pins.
- Make sure input signal trace is well matched.
- Do not route any traces that carrying switching signal close to the charge pump traces and external VCO.

10.2 Layout Example

Figure 34. Recommended Layout

11 Device and Documentation Support

11.1 Device Support

11.1.1 Development Support

Texas Instruments has several software tools to aid in the development at [www.ti.com.](http://www.TI.com/) Among these tools are:

- Codeloader to understand how to program the EVM board.
- Clock Design Tool for designing loop filters, simulating phase noise, and simulating spurs.
- EVM board instructions for seeing typical measured data with detailed measurement conditions and a complete design.
- Clock Architect for designing and simulating the device and understanding how it might work with other devices.

11.2 Documentation Support

11.2.1 Related Documentation

The following are recommended reading.

- AN-1879 *Fractional N Frequency Synthesis* [\(SNAA062](http://www.ti.com/lit/pdf/SNAA062))
- *PLL Performance, Simulation, and Design Handbook* ([SNAA106\)](http://www.ti.com/lit/pdf/SNAA106)

11.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms](http://www.ti.com/corp/docs/legal/termsofuse.shtml) of [Use.](http://www.ti.com/corp/docs/legal/termsofuse.shtml)

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Design [Support](http://support.ti.com/) *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.4 Trademarks

E2E is a trademark of Texas Instruments.

11.5 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.6 Glossary

[SLYZ022](http://www.ti.com/lit/pdf/SLYZ022) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check<http://www.ti.com/productcontent>for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

MECHANICAL DATA

All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α.

- **B.** This drawing is subject to change without notice.
- QFN (Quad Flatpack No-Lead) Package configuration. С.
- The package thermal pad must be soldered to the board for thermal and mechanical performance. D.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. Package complies to JEDEC MO-220 variation VJJD-2.

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